Light-Emitting Diodes: Materials, Devices, and Applications for Solid State Lighting XXII

Jong Kyu Kim Michael R. Krames Martin Strassburg Li-Wei Tu Editors

29–31 January 2018 San Francisco, California, United States

Sponsored and Published by SPIE

Volume 10554

Proceedings of SPIE 0277-786X, V. 10554

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

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Author(s), "Title of Paper," in Light-Emitting Diodes: Materials, Devices, and Applications for Solid State Lighting XXII, edited by Jong Kyu Kim, Michael R. Krames, Martin Strassburg, Li-Wei Tu, Proceedings of SPIE Vol. 10554 (SPIE, Bellingham, WA, 2018) Seven-digit Article CID Number.

ISSN: 0277-786X ISSN: 1996-756X (electronic)

ISBN: 9781510615939 ISBN: 9781510615946 (electronic)

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Printed in the United States of America Vm7 i ffUb 5ggc WUhYgž a Wži bXYf WbgY Zfca GD-9.

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